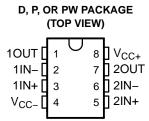
SLOS477A-JUNE 2005-REVISED JULY 2005

FEATURES

- Operating Voltage...±2 V to ±18 V
- Low Offset Voltage...1 mV Max at 25°C, TL5580A
- Wide GBW...12 MHz Typ
- Slew Rate...5 V/μs Typ
- Low THD...0.0005% Typ
- Low-Noise Voltage...7 nV/√Hz at 1 kHz Typ

APPLICATIONS

- Audio
- Test Equipment
- Industrial Process Controls
- Data-Acquisition Systems
- Active Filters
- Power-Supply Regulation



DESCRIPTION/ORDERING INFORMATION

The TL5580 is a dual bipolar operational amplifier that combines both high dc and ac performance with its low offset voltage, high-gain bandwidth, low harmonic distortion, and low-noise characteristics. In addition, its output is capable of driving $600-\Omega$ loads. All these characteristics make the device ideally suited for use in audio, active filtering, and industrial measurement applications.

ORDERING INFORMATION

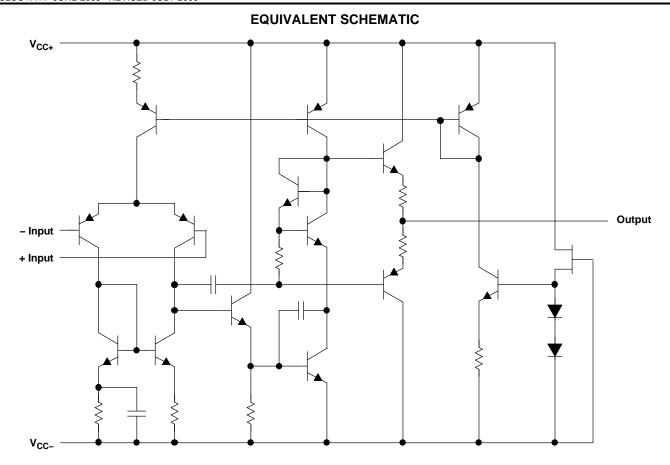
T _A	V _{IO} (25°C, MAX)	PACI	KAGE ⁽¹⁾	ORDERABLE PART NUMBER	TOP-SIDE MARKING
		PDIP – P	Tube of 50	TL5580IP	TL5580IP
		2010	Tube of 75	TL5580ID	Z5580
	Standard grade 1.5 mV	SOIC – D	Reel of 2500	TL5580IDR	25560
		TSSOP – PW	Tube of 150	TL5580IPW	Z5580
–40°C to 85°C		1330P - PW	Reel of 2000	TL5580IPWR	25560
-40 C to 65 C		PDIP – P	Tube of 50	TL5580AIP	TL5580AIP
		SOIC - D	Tube of 75	TL5580AID	Z5580A
	A grade 1 mV	30IC - D	Reel of 2500	TL5580AIDR	Z5560A
		TSSOP – PW	Tube of 150	TL5580AIPW	Z5580A
		1330P - FW	Reel of 2000	TL5580AIPWR	2000A

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.







TL5580, TL5580A **DUAL LOW-NOISE WIDE-BANDWIDTH PRECISION AMPLIFIER**

SLOS477A-JUNE 2005-REVISED JULY 2005

Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
$V_{CC\pm}$	Supply voltage			±18	V
VI	Input voltage (any input)			±15	V
V_{ID}	Differential input voltage			±30	V
Io	Output current			±50	mA
		D package		97	
θ_{JA}	Package thermal impedance (2)(3)	P package		±18 ±15 ±30 ±50 97 85 149	°C/W
		PW package			
TJ	Operating virtual junction temperature			150	°C
T _{stg}	Storage temperature range		-60	125	°C

⁽¹⁾ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating" conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

Recommended Operating Conditions

		MIN	MAX	UNIT
V _{CC+}	Cupply voltage	2	16	\/
V _{CC} -	Supply voltage	-2	-16	V
T _A	Operating free-air temperature	-40	85	°C

Maximum power dissipation is a function of $T_J(max)$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(max) - T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability. The package thermal impedance is calculated in accordance with JESD 51-7.

TL5580, TL5580A DUAL LOW-NOISE WIDE-BANDWIDTH PRECISION AMPLIFIER

SLOS477A-JUNE 2005-REVISED JULY 2005



Electrical Characteristics

 $V_{CC\pm}$ = ±15 V (unless otherwise noted)

	PARAMETER		TEST CONDITIONS	TA	MIN	TYP	MAX	UNIT	
V		TI FEROA		25°C		0.3	1		
	land offert college	TL5580A	D <4010	-40°C to 85°C			1.35	\/	
V _{IO}	Input offset voltage	TI 5500	$R_S \le 10 \text{ k}\Omega$	25°C		0.3	1.5	mV	
		TL5580		-40°C to 85°C			2		
αV_{IO}	Average temperature coeff offset voltage	icient of input		-40°C to 85°C		1.8	5	μV/°C	
-	land offers and an armount			25°C	25°C 5		75		
I _{IO}	Input offset current			-40°C to 85°C			100	nA	
	lament bing assument			25°C		100	500	nA	
I _{IB}	Input bias current			-40°C to 85°C			800		
	Large-signal differential-vo	Itage	D > 2 kO V 140 V	25°C	90	110		dB	
A_{VD}	amplification	-	$R_L \ge 2 \text{ k}\Omega, V_O = \pm 10 \text{ V}$	-40°C to 85°C	87				
	Outrout valta na avvia a		D > 0 lo	25°C	12.75 - 12.25	±13.5			
V _{OM}	Output voltage swing		$R_L \ge 2 k\Omega$	-40°C to 85°C	12.5 –12			V	
.,	Common model innut valte			25°C	±13	±13.5		V	
V_{ICR}	Common-mode input voltage	ge range		-40°C to 85°C	±12			V	
OMPD	0		$R_S \le 10 \text{ k}\Omega$,	25°C	90	110		-ID	
CMRR	Common-mode rejection ra	atio	$V_{ICR} = -12 \text{ V to } 12 \text{ V}$	-40°C to 85°C	85			dB	
1. (1)	Complementaria maia stiana ma	4: _~	D <4010	25°C	85	110		٩D	
k _{SVR} ⁽¹⁾	Supply-voltage rejection ra	τιο	$R_{S} \le 10 \text{ k}\Omega$	-40°C to 85°C	83			dB	
	Cumply gurrent (all generalities			25°C		6	9	9	
Icc	Supply current (all amplifie	rs)		-40°C to 85°C			12	mA	

⁽¹⁾ Measured with $V_{CC\pm}$ varied simultaneously

Operating Characteristics

 $V_{CC\pm} = \pm 15 \text{ V}, T_A = 25^{\circ}\text{C} \text{ (unless otherwise noted)}$

	PARAMETER	TEST CONDITIONS	TYP	UNIT
SR	Slew rate at unity gain	$R_L \ge 2 \text{ k}\Omega$	5	V/μs
GBW	Gain bandwidth product	f = 10 kHz	12	MHz
THD	Total harmonic distortion	$V_O = 5 \text{ V}, R_L = 2 \text{ k}\Omega, f = 1 \text{ kHz}, A_{VD} = 20 \text{ dB}$	0.0005	%
V_n	Equivalent input noise voltage	f = 1 kHz	7	nV/√ Hz

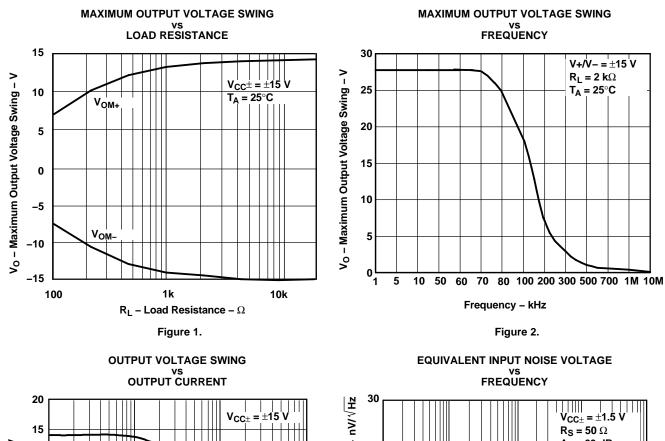
SLOS477A-JUNE 2005-REVISED JULY 2005

V+/V-=±15 V

 $R_L = 2 k\Omega$

 $T_A = 25^{\circ}C$

TYPICAL CHARACTERISTICS



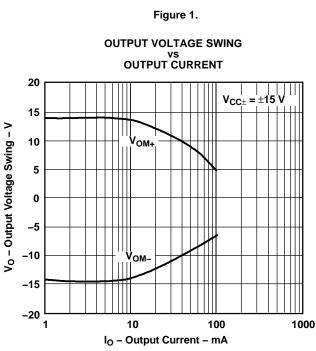
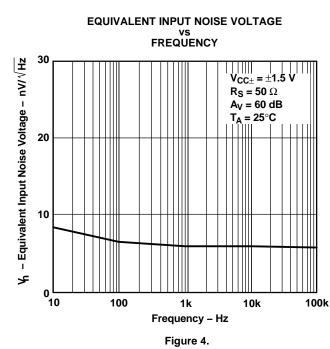
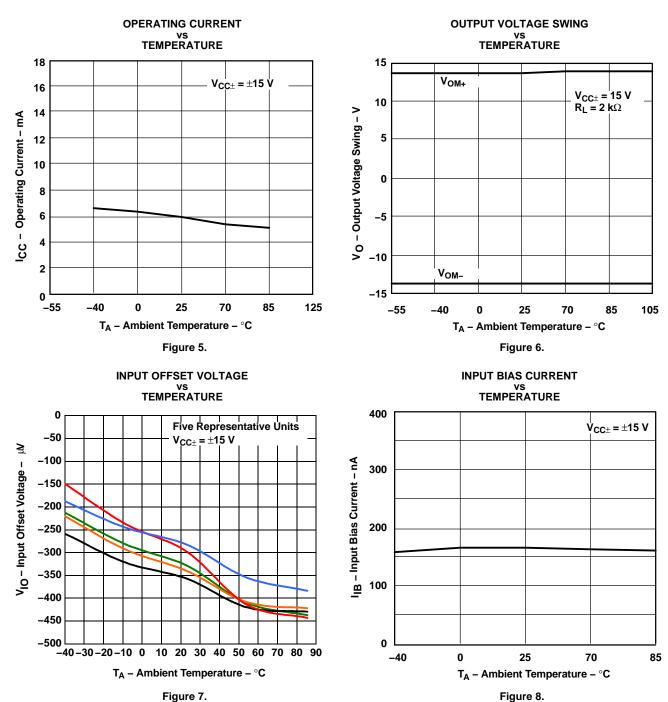


Figure 3.



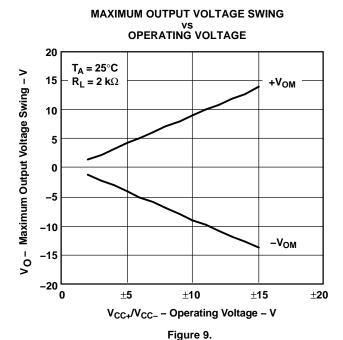


TYPICAL CHARACTERISTICS (continued)





TYPICAL CHARACTERISTICS (continued)



TOTAL HARMONIC DISTORTION VS OUTPUT VOLTAGE

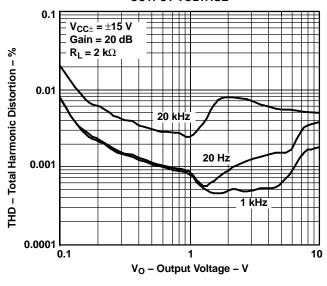
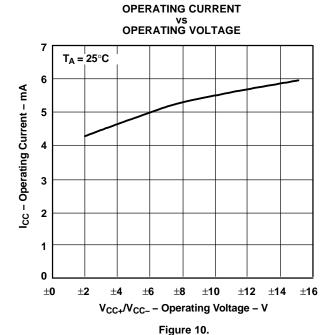


Figure 11.



VOLTAGE GAIN, PHASE vs FREQUENCY

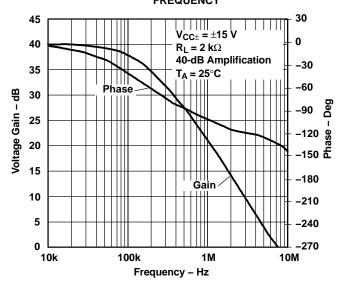


Figure 12.





10-Dec-2020

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
							(6)				
TL5580AID	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	Z5580A	Samples
TL5580AIDR	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	Z5580A	Samples
TL5580AIP	ACTIVE	PDIP	Р	8	50	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 85	TL5580AIP	Samples
TL5580AIPWR	ACTIVE	TSSOP	PW	8	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	Z5580A	Samples
TL5580IDR	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	Z5580	Samples
TL5580IP	ACTIVE	PDIP	Р	8	50	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 85	TL5580IP	Samples
TL5580IPWR	ACTIVE	TSSOP	PW	8	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	Z5580	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.



PACKAGE OPTION ADDENDUM

10-Dec-2020

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





Α0	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

All difficultions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TL5580AIDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TL5580AIPWR	TSSOP	PW	8	2000	330.0	12.4	7.0	3.6	1.6	8.0	12.0	Q1
TL5580IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TL5580IPWR	TSSOP	PW	8	2000	330.0	12.4	7.0	3.6	1.6	8.0	12.0	Q1

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TL5580AIDR	SOIC	D	8	2500	340.5	338.1	20.6
TL5580AIPWR	TSSOP	PW	8	2000	853.0	449.0	35.0
TL5580IDR	SOIC	D	8	2500	340.5	338.1	20.6
TL5580IPWR	TSSOP	PW	8	2000	853.0	449.0	35.0



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES:

- 1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- 4. This dimension does not include interlead flash.
- 5. Reference JEDEC registration MS-012, variation AA.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



P (R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-001 variation BA.





SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153, variation AA.



SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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